

# 23A005

### **23A005 Information**

Heisener.com	Part Number Manufacturer Category Description Package	23A005 Microsemi Corporation Discrete Semiconductor Products Transistors - Bipolar (BJT) - RF TRANS RF BIPO 3W 400MA 55BT2 55BT For the pricing/inventory/lead time, please contact	
For Reference Only		us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

# **Certified Quality**

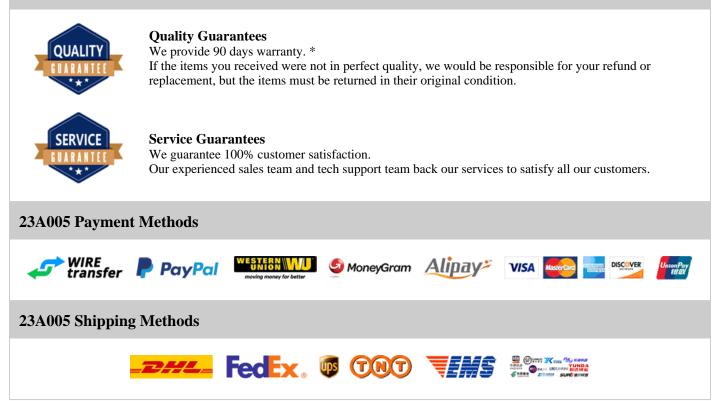
Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



## 23A005 Specifications

Manufacturer Part Number	23A005	
Manufacturer	Microsemi Corporation	
Category	Discrete Semiconductor Products	
	Transistors - Bipolar (BJT) - RF	
Package	55BT	
Series	-	
Transistor Type	NPN	
Voltage - Collector Emitter Breakdown (Max)	22V	
Frequency - Transition	4.3GHz	
Noise Figure (dB Typ @ f)	-	
Gain	8.5dB ~ 9.5dB	
Power - Max	3W	
DC Current Gain (hFE) (Min) @ Ic, Vce	20 @ 100mA, 5V	
Current - Collector (Ic) (Max)	400mA	
Operating Temperature	200°C (TJ)	
Mounting Type	Chassis Mount	
Package / Case	55BT	
Supplier Device Package	55BT	
	Report errors?	

#### 23A005 Guarantees



If you have any question about 23A005, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com